

NPN Epitaxial Planar Silicon Transistor

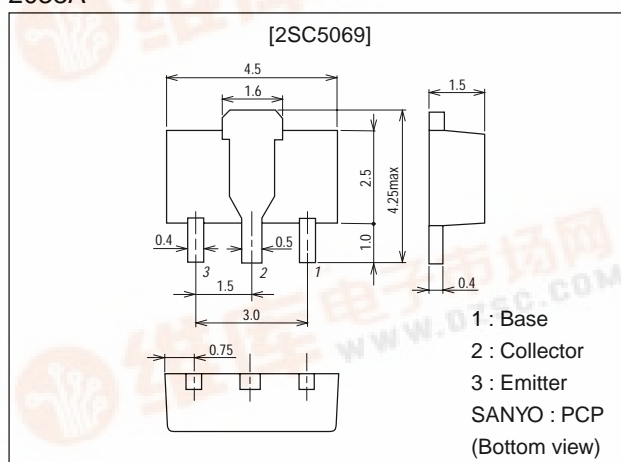
**SANYO****2SC5069****Low-Frequency General-Purpose Amplifier,  
Driver Applications****Features**

- High current capacity.
- Adoption of MBIT process.
- High DC current gain.
- Low collector-to-emitter saturation voltage.
- High  $V_{EBO}$ .

**Package Dimensions**

unit:mm

2038A

**Specifications****Absolute Maximum Ratings at  $T_a = 25^\circ\text{C}$** 

Parameter	Symbol	Conditions	Ratings	Unit
Collector-to-Base Voltage	$V_{CBO}$		30	V
Collector-to-Emitter Voltage	$V_{CEO}$		25	V
Emitter-to-Base Voltage	$V_{EBO}$		15	V
Collector Current	$I_C$		2	A
Collector Current (Pulse)	$I_{CP}$		4	A
Base Current	$I_B$		0.4	A
Collector Dissipation	$P_C$	Mounted on ceramic board (250mm <sup>2</sup> ×0.8mm)	1.5	W
Junction Temperature	$T_j$		150	°C
Storage Temperature	$T_{stg}$		-55 to +150	°C

**Electrical Characteristics at  $T_a = 25^\circ\text{C}$** 

Parameter	Symbol	Conditions	Ratings			Unit
			min	typ	max	
Collector Cutoff Current	$I_{CBO}$	$V_{CB}=20\text{V}, I_E=0$			100	nA
Emitter Cutoff Current	$I_{EBO}$	$V_{EB}=10\text{V}, I_C=0$			100	nA
DC Current Gain	$h_{FE1}$	$V_{CE}=5\text{V}, I_C=500\text{mA}$	800	1500	3200	
	$h_{FE2}$	$V_{CE}=5\text{V}, I_C=1\text{A}$	600			
Gain-Bandwidth Product	$f_T$	$V_{CE}=10\text{V}, I_C=50\text{mA}$		260		MHz
Output Capacitance	$C_{ob}$	$V_{CB}=10\text{V}, f=1\text{MHz}$		27		pF

Marking :CU

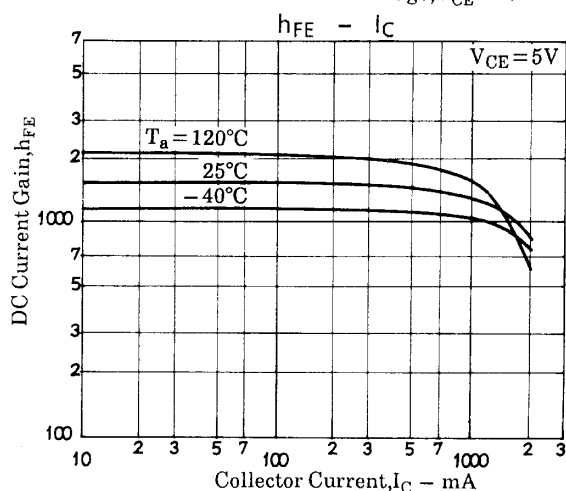
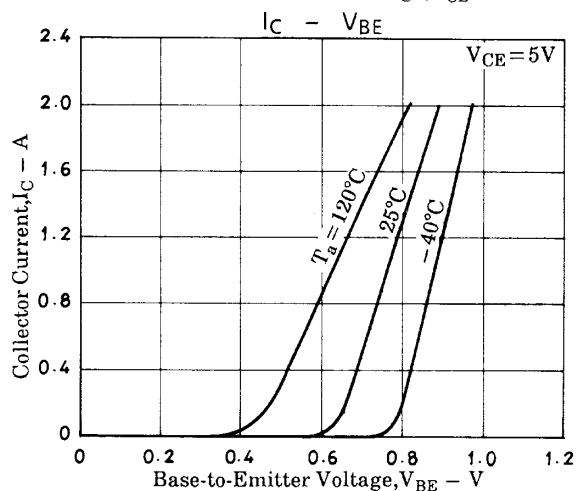
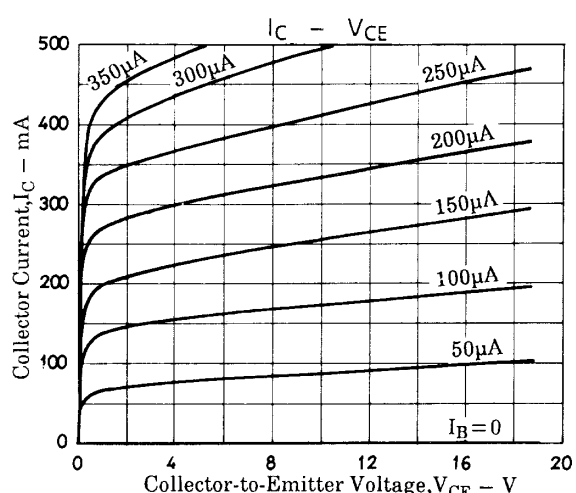
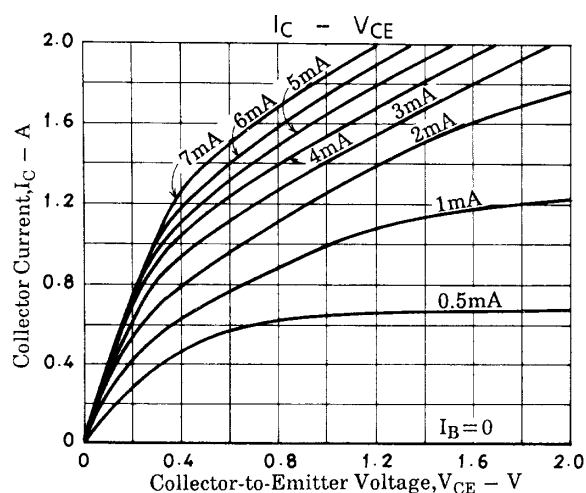
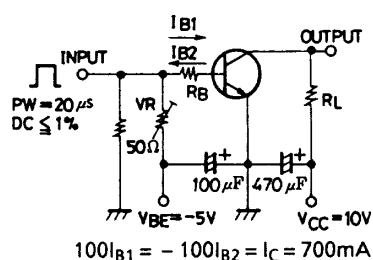
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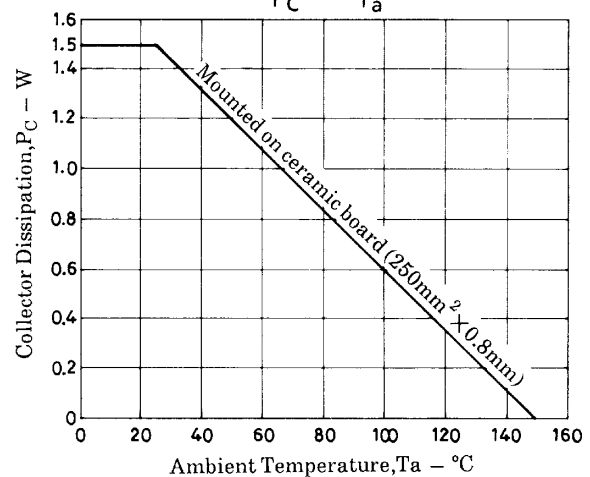
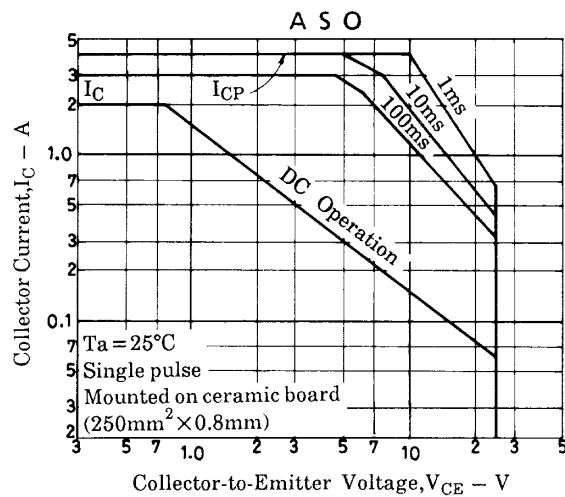
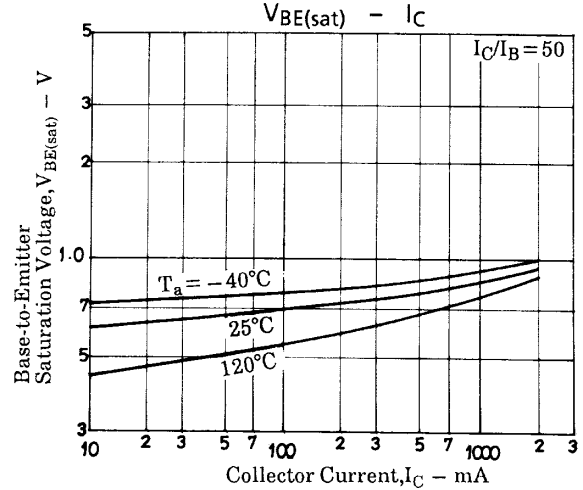
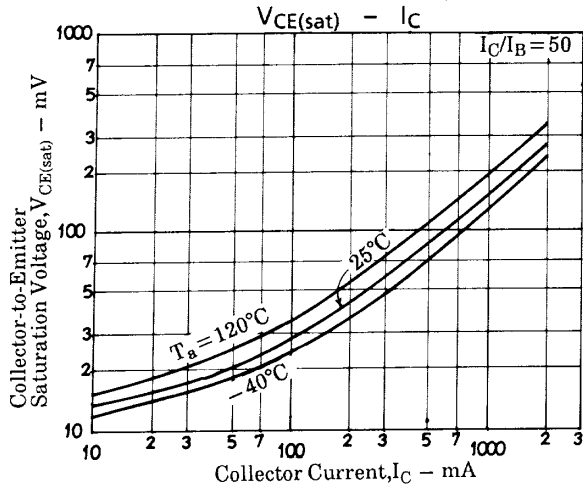
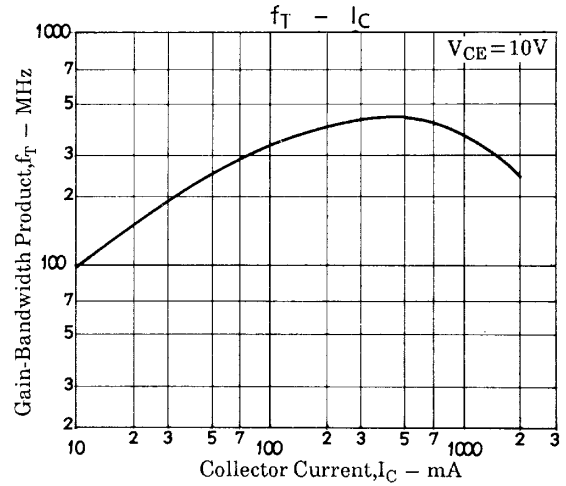
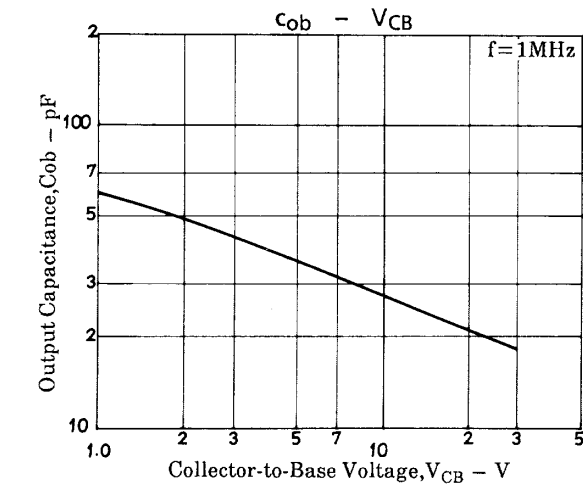
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Parameter	Symbol	Conditions	Ratings			Unit
			min	typ	max	
Collector-to-Emitter Saturation Voltage	$V_{CE(sat)}$	$I_C=1A, I_B=20mA$		0.15	0.5	V
Base-to-Emitter Saturation Voltage	$V_{BE(sat)}$	$I_C=1A, I_B=20mA$		0.85	1.2	V
Collector-to-Base Breakdown Voltage	$V_{(BR)CBO}$	$I_C=10\mu A, I_E=0$	30			V
Collector-to-Emitter Breakdown Voltage	$V_{(BR)CEO}$	$I_C=1mA, R_{BE}=\infty$	25			V
Emitter-to-Base Breakdown Voltage	$V_{(BR)EBO}$	$I_E=10\mu A, I_C=0$	15			V
Turn-ON Time	$t_{on}$	See specified Test Circuit		0.14		$\mu s$
Storage Time	$t_{stg}$	See specified Test Circuit		1.35		$\mu s$
Fall Time	$t_f$	See specified Test Circuit		0.1		$\mu s$

### Switching Time Test Circuit



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